

SN54ABT162245, SN74ABT162245 16-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

SCBS239C – MARCH 1993 – REVISED OCTOBER 1994

- A-Port Outputs Have Equivalent 25- Ω Series Resistors, So No External Resistors Are Required
- Members of the Texas Instruments *Widebus*™ Family
- State-of-the-Art *EPIC-II B*™ BiCMOS Design Significantly Reduces Power Dissipation
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- Typical V_{OLP} (Output Ground Bounce) < 1 V at $V_{CC} = 5$ V, $T_A = 25^\circ\text{C}$
- Distributed V_{CC} and GND Pin Configuration Minimizes High-Speed Switching Noise
- Flow-Through Architecture Optimizes PCB Layout
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings

description

The 'ABT162245 are 16-bit (dual-octal) noninverting 3-state transceivers designed for synchronous two-way communication between data buses. The control function implementation minimizes external timing requirements.

These devices can be used as two 8-bit transceivers or one 16-bit transceiver. They allow data transmission from the A bus to the B bus or from the B bus to the A bus depending upon the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses are effectively isolated.

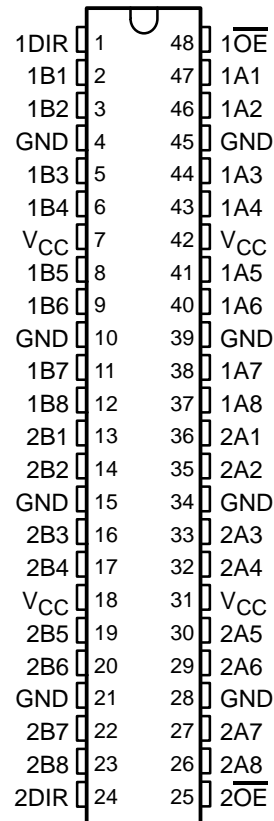
The A-port outputs, which are designed to source or sink up to 12 mA, include 25- Ω series resistors to reduce overshoot and undershoot.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN74ABT162245 is available in TI's shrink small-outline package (DL), which provides twice the I/O pin count and functionality of standard small-outline packages in the same printed-circuit-board area.

The SN54ABT162245 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74ABT162245 is characterized for operation from -40°C to 85°C .

SN54ABT162245 . . . WD PACKAGE
SN74ABT162245 . . . DGG OR DL PACKAGE
(TOP VIEW)



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 **TEXAS
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SN54ABT162245, SN74ABT162245

16-BIT BUS TRANSCEIVERS

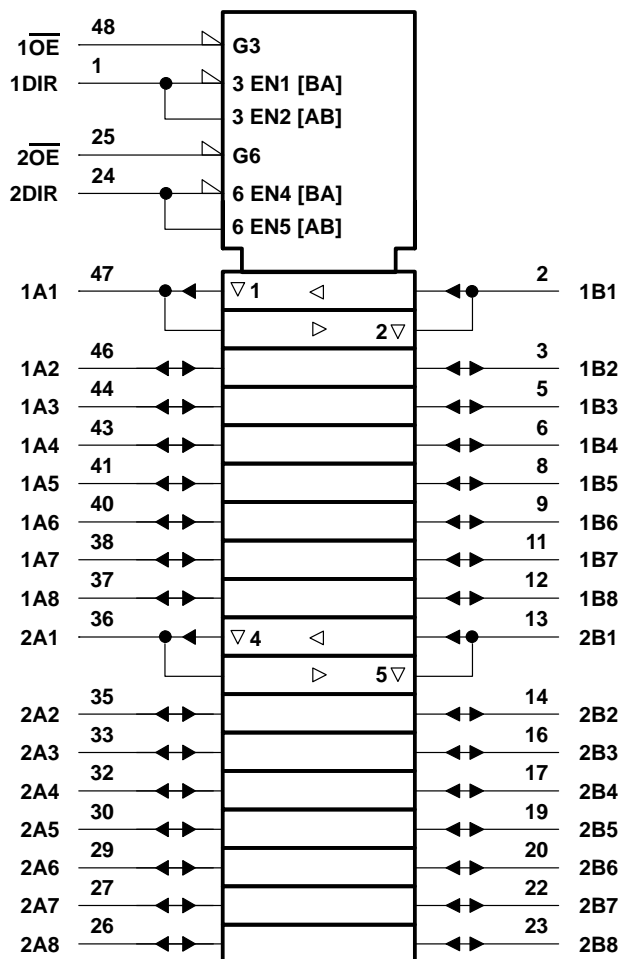
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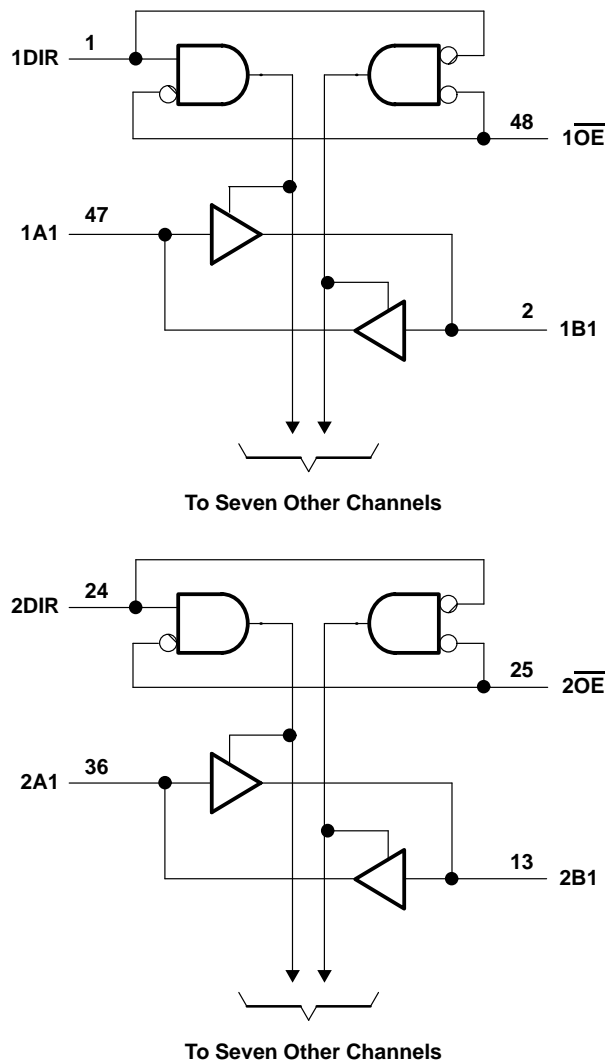
FUNCTION TABLE
(each 8-bit section)

INPUTS		OPERATION
\overline{OE}	DIR	
L	L	B data to A bus
L	H	A data to B bus
H	X	Isolation

logic symbol†



logic diagram (positive logic)



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}	–0.5 V to 7 V
Input voltage range, V_I (except I/O ports) (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state or power-off state, V_O	–0.5 V to 5.5 V
Current into any output in the low state, I_O : SN54ABT162245 (B port)	96 mA
SN74ABT162245 (B port)	128 mA
SN54/74ABT162245 (A port)	30 mA
Input clamp current, I_{IK} ($V_I < 0$)	–18 mA
Output clamp current, I_{OK} ($V_O < 0$)	–50 mA
Maximum power dissipation at $T_A = 55^\circ\text{C}$ (in still air) (see Note 2): DGG package	0.85 W
DL package	1.2 W
Operating free-air temperature range, T_A : SN54ABT162245	–55°C to 125°C
SN74ABT162245	–40°C to 85°C
Storage temperature range	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils. For more information, refer to the *Package Thermal Considerations* application note in the 1994 *ABT Advanced BiCMOS Technology Data Book*, literature number SCBD002B.

recommended operating conditions (see Note 3)

			SN54ABT162245		SN74ABT162245		UNIT
			MIN	MAX	MIN	MAX	
V _{CC}	Supply voltage		4.5	5.5	4.5	5.5	V
V _{IH}	High-level input voltage		2		2		V
V _{IL}	Low-level input voltage			0.8		0.8	V
V _I	Input voltage		0	V _{CC}	0	V _{CC}	V
I _{OH}	High-level output current	B port	−24		−32		mA
		A port	−12		−12		
I _{OL}	Low-level output current	B port	48		64		mA
		A port	12		12		
Δt/Δv	Input transition rise or fall rate	Outputs enabled	10		10		ns/V
T _A	Operating free-air temperature		−55	125	−40	85	°C

NOTE 3: Unused or floating pins (input or I/O) must be held high or low.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A = 25°C			SN54ABT162245		SN74ABT162245		UNIT
				MIN	TYP†	MAX	MIN	MAX	MIN	MAX	
V _{IK}		V _{CC} = 4.5 V, I _I = –18 mA		–1.2			–1.2		–1.2		V
V _{OH}	A port	V _{CC} = 5 V, I _{OH} = –1 mA		3.8			2.5		2.5		V
		V _{CC} = 4.5 V	I _{OH} = –1 mA	3.3			3		3		
			I _{OH} = –3 mA	3.1			3		3.1		
			I _{OH} = –12 mA	2.6*					2.6		
	B port	V _{CC} = 5 V, I _{OH} = –3 mA		3			3		3		
		V _{CC} = 4.5 V	I _{OH} = –3 mA	2.5			2.5		2.5		
			I _{OH} = –24 mA				2				
			I _{OH} = –32 mA	2*					2		
V _{OL}	A port	V _{CC} = 4.5 V	I _{OL} = 12 mA		0.8		0.8		0.8		V
	B port		I _{OL} = 48 mA		0.45		0.45		0.45		
			I _{OL} = 64 mA		0.55*		0.55		0.55		
I _I	Control inputs	V _{CC} = 5.5 V, V _I = V _{CC} or GND		±1			±1		±1		μA
	A or B ports			±20			±20		±20		
I _{OZH} ‡		V _{CC} = 5.5 V, V _O = 2.7 V		10			10		10		μA
I _{OZL} ‡		V _{CC} = 5.5 V, V _O = 0.5 V		–10			–10		–10		μA
I _{off}		V _{CC} = 0, V _I or V _O ≤ 4.5 V		±100					±100		μA
I _{CEX}	Outputs high	V _{CC} = 5.5 V, V _O = 5.5 V		50			50		50		μA
I _{O§}	A port	V _{CC} = 5.5 V, V _O = 2.5 V		–25	–50	–100	–25	–100	–25	–100	mA
	B port			–50	–100	–180	–50	–180	–50	–180	
I _{CC}	A or B ports	V _{CC} = 5.5 V, I _O = 0, V _I = V _{CC} or GND	Outputs high	2			2		2		mA
			Outputs low	32			32		32		
			Outputs disabled	2			2		2		
ΔI _{CC¶}	Data inputs	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND	Outputs enabled	1			2		2		mA
			Outputs disabled	0.05			1		0.05		
	Control inputs	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND		1.5			1.5		1.5		
C _i		V _I = 2.5 V or 0.5 V		3							pF
C _{io}		V _O = 2.5 V or 0.5 V		6							pF

* On products compliant to MIL-STD-883, Class B, this parameter does not apply.

† All typical values are at V_{CC} = 5 V.

‡ The parameters I_{OZH} and I_{OZL} include the input leakage current.

§ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

¶ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 5$ V, $T_A = 25^\circ\text{C}$			SN54ABT162245		SN74ABT162245		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	B	1	2.2	3.4	1	4.1	1	3.9	ns
t_{PHL}			1	2.3	3.7	1	4.4	1	4.2	
t_{PLH}	B	A	1	2.7	4.1	1	4.9	1	4.6	ns
t_{PHL}			1.5	3.1	4.6	1.5	5.2	1.5	5.1	
t_{PZH}	\overline{OE}	B	1	3.6	5.2	1	6.4	1	6.3	ns
t_{PZL}			1	3.7	5.4	1	6.5	1	6.4	
t_{PHZ}	\overline{OE}	B	2	4.4	5.8	2	6.4	2	6.3	ns
t_{PLZ}			1.5	3.3	4.7	1.5	5.6	1.5	5.2	
t_{PZH}	\overline{OE}	A	1.5	4.1	6	1.5	7.2	1.5	7.1	ns
t_{PZL}			1.5	4.3	6.1	1.5	7.3	1.5	7	
t_{PHZ}	\overline{OE}	A	2	4.5	6.1	2	6.8	2	6.6	ns
t_{PLZ}			1.5	3.7	5.1	1.5	6.1	1.5	5.7	

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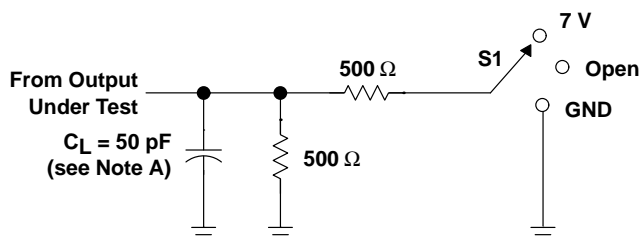
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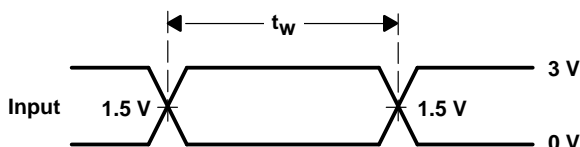
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PARAMETER MEASUREMENT INFORMATION

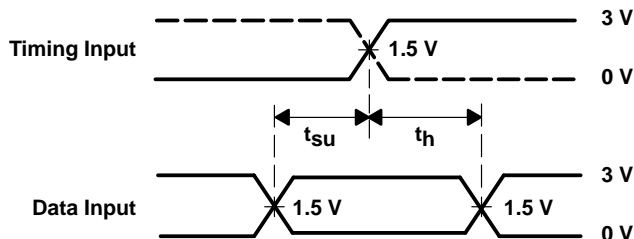


LOAD CIRCUIT FOR OUTPUTS

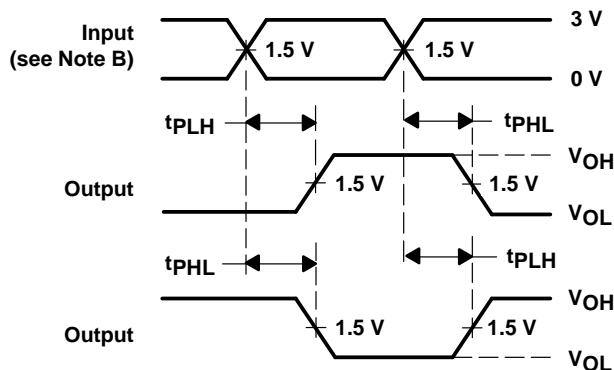
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	7 V
t_{PHZ}/t_{PZH}	Open



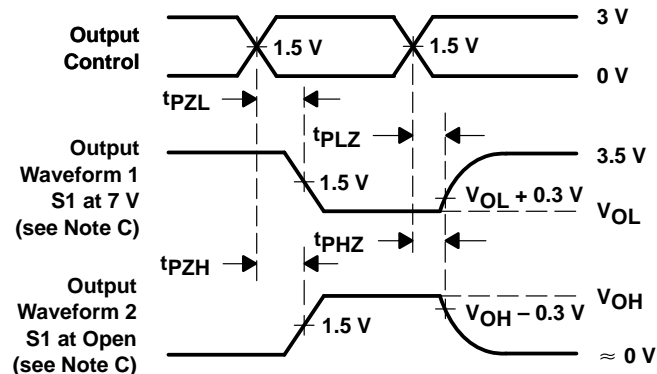
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

- NOTES: A. C_L includes probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2.5 \text{ ns}$, $t_f \leq 2.5 \text{ ns}$.
- C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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